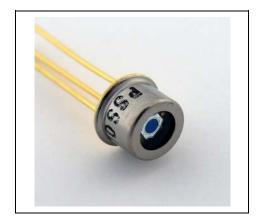
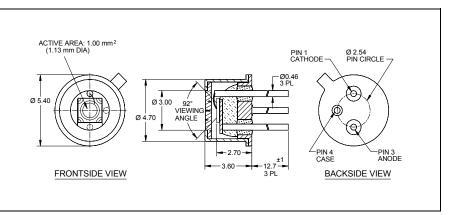


Pacific Silicon Sensor Series 9 Data Sheet Part Description AD1100-9-TO52-S1 Order # 06-018





FEATURES

- \varnothing 1.13 mm active area
- Low slope multiplication curve
- High speed, low noise
- NIR enhanced

DESCRIPTION

1.0 mm² High Speed, Low Noise Avalanche Photodiode with N on P construction. Hermetically packaged in a TO-52-S1 with a clear borosilicate glass window cap.

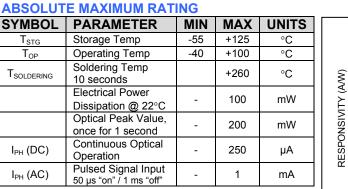
APPLICATIONS

- High speed optical
- communications

 Laser range finder
- Laser range finder
 Medical equipment
- High speed photometry



SPECTRAL RESPONSE at M = 100



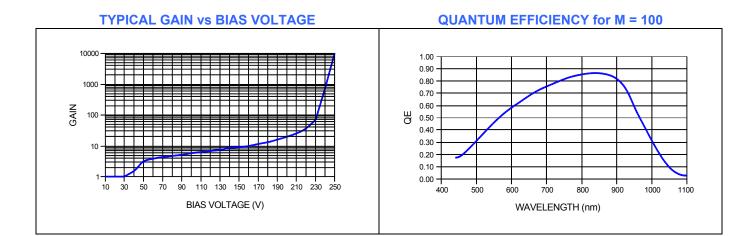
70 60 50 40 30 20 10 0 400 500 600 700 800 900 1000 1100 WAVELENGTH (nm)

ELECTRO-OPTICAL CHARACTERISTICS @ 22 °C

SYMBOL	CHARACTERISTIC	TEST CONDITIONS	MIN	TYP	MAX	UNITS
ID	Dark Current	M = 100*		4.0	10	nA
С	Capacitance	M = 100*		3.0		pF
V_{BR}	Breakdown Voltage	$I_D = 2 \mu A$	180	240		V
	Temperature Coefficient of V _{BR}			1.55		V/K
	Responsivity	M = 100; = 0 V; λ = 905 nm	55	60		A/W
$\Delta f_{\rm 3dB}$	Bandwidth	-3dB		0.3		GHz
tr	Rise Time	M = 100		1300		ps
	Optimum Gain		40	60		
	"Excess Noise" factor	M = 100		2.5		
	"Excess Noise" index	M = 100		0.2		
	Noise Current	M = 100		0.15		pA/Hz ^{1/2}
	Max Gain		200			
NEP	Noise Equivalent Power	M = 100; λ = 905 nm		8.0 X 10 ⁻¹⁴		W/Hz ^{1/2}

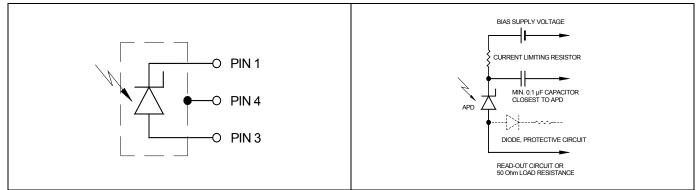
* Measurement conditions: Setup of photo current 10 nA at M = 1 and irradiated by a 880 nm, 80 nm bandwidth LED. Increase the photo current up to 1 μA, (M = 100) by internal multiplication due to an increasing bias voltage.

Disclaimer: Due to our policy of continued development, specifications are subject to change without notice.



DEVICE SCHEMATIC

SUGGESTED CIRCUIT SCHEMATIC



APPLICATION NOTES

- Current should be limited by a protecting resistor or current limiting IC inside the power supply.
- Use of low noise read-out IC.
- For high gain applications (M>50) bias voltage should be temperature compensated.
- For low light level applications, blocking of ambient light should be used.

HANDLING PRECAUTIONS:

- Soldering temperature 260°C for 10 seconds max. The device must be protected against solder flux vapor.
- Minimum pin length 2 mm
- · ESD protection Standard precautionary measures are sufficient.
- Storage Store devices in conductive foam.
- Avoid skin contact with window.
- · Clean window with Ethyl alcohol if necessary.
- Do not scratch or abrade window.

USA:

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Pacific Silicon Sensor: AD1100-9-TO52-S1